**Vishay Semiconductors** 

Ultralow V<sub>F</sub> Ultrafast Rectifier, 6 A FRED Pt<sup>®</sup>



www.vishay.com

SlimDPAK (TO-252AE)

# LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub> 6 A				
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub>	0.98 V			
t <sub>rr</sub> (typ.)	34 ns			
T <sub>J</sub> max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Single			

#### **FEATURES**

- Ultrafast recovery time, extremely low  $V_{\mathsf{F}}$  and soft recovery
- For PFC CCM operation
- Low forward voltage drop, low power losses
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified

- Automotive ordering code: base P/NHM3, meets JESD 201 class 2 whisker test

• Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

## **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V	
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 158 °C	6	A	
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25 \ ^{\circ}C$ , 10 ms sine pulse wave	80		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage V <sub>F</sub>	V	I <sub>F</sub> = 6 A	-	1.15	1.35	V
	I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C	-	0.98	1.15		
Reverse leakage current	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	5	
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	125	μA
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	10	-	pF

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t <sub>rr</sub>	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	45	-	ns
		$I_F = 1 \text{ A}, \text{ d}_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	34	-	
Reverse recovery time		I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>RR</sub> = 0.25 A		-	-	50	
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 6 A dI <sub>F</sub> /dt = 500 A/μs V <sub>R</sub> = 400 V	-	65	-	
		T <sub>J</sub> = 125 °C		-	90	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	9.5	-	A
		T <sub>J</sub> = 125 °C		-	13.5	-	
Reverse recovery charge	Q <sub>rr</sub>	$T_J = 25 \ ^{\circ}C$		-	320	-	nC
		T <sub>J</sub> = 125 °C		-	620	-	пс

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction to mount	R <sub>thJM</sub>		-	-	2.5	°C/W
Weight			-	0.20	-	g
Marking device		Case style SlimDPAK (TO-252AE)	6EVL06			

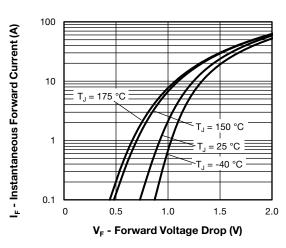
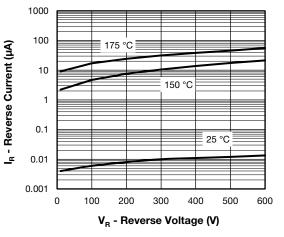
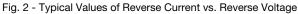
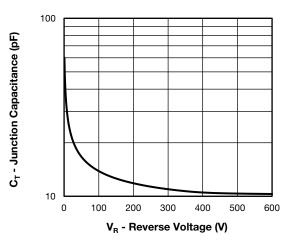


Fig. 1 - Typical Forward Voltage Drop Characteristics





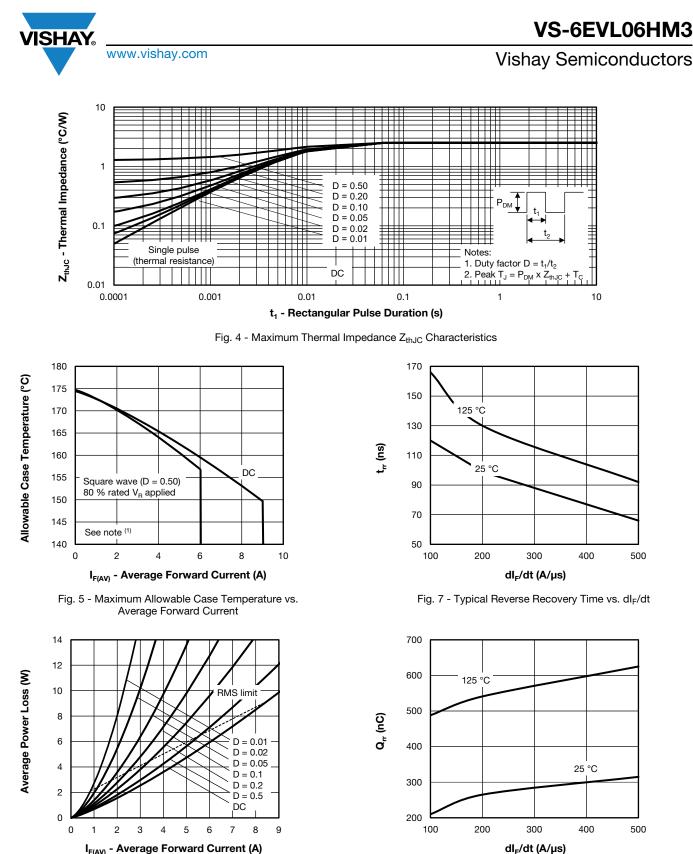




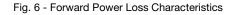
 
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I<sub>F(AV)</sub> - Average Forward Current (A)



Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

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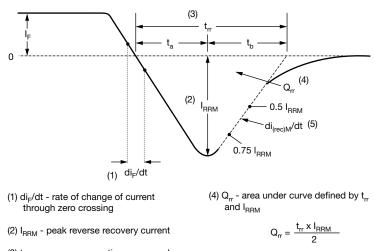
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Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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# VS-6EVL06HM3

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(3) t<sub>rr</sub> - reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.

(5)  $di_{(rec)M}$ /dt - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions

### **ORDERING INFORMATION TABLE**

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**Device code** vs-6 Ε ٧ 06 н **M**3 L (2) 3 (7 1 4 5 6 8 Vishay Semiconductors product 2 Current rating (6 = 6 A) 3 Circuit configuration: E = single die V = SlimDPAK 5 Process type: L = ultralow V<sub>F</sub> ultrafast rectifier Voltage code (06 = 600 V) 6 H = AEC-Q101 qualified 8 Environmental digit: M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-6EVL06HM3/I	0.20	I	4500	13"diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96081				
Part marking information	www.vishay.com/doc?96085			
Packaging information	www.vishay.com/doc?88869			

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SlimDPAK

#### **DIMENSIONS** in inches (millimeters)





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